

# STPS1L60

## Power Schottky rectifier

#### **Features**

- Negligible switching losses
- Low forward voltage drop
- Surface mount miniature packages
- Avalanche capability specified

### **Description**

Axial and surface mount power Schottky rectifiers suited to switched mode power supplies and high frequency DC to DC converters.

Packaged in SMA, STmite flat and DO-41, this device is especially intended for use in low voltage, high frequency inverters and small battery chargers.

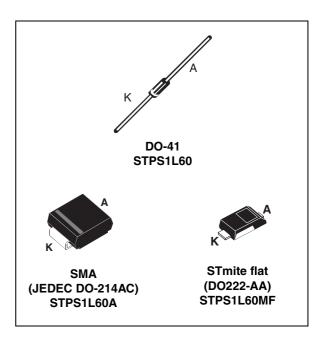


Table 1. Device summary

Symbol	Value
I <sub>F(AV)</sub>	1 A
V <sub>RRM</sub>	60 V
T <sub>j</sub> (max)	150 °C
V <sub>F</sub> (max)	0.56 V

STPS1L60 **Characteristics** 

### **Characteristics**

Table 2. Absolute ratings (limiting values)

Symbol		Value	Unit		
$V_{RRM}$	Repetitive peak reverse vol	tage		60	V
			STmite flat	2	Α
I <sub>F(RMS)</sub>	Forward rms current		SMA, DO-41	10	Α
		SMA	$T_L = 130 {}^{\circ}\text{C}  \delta = 0.5$		
I <sub>F(AV)</sub>	Average forward current	DO-41	T <sub>L</sub> = 120 °C δ = 0.5	1	Α
		STmite flat	$T_{C} = 135  ^{\circ}\text{C}  \delta = 0.5$		
I <sub>FSM</sub>	Surge non repetitive forwar	d current	t <sub>p</sub> =10 ms sinusoidal	40	Α
P <sub>ARM</sub>	Repetitive peak avalanche power $t_p = 1 \mu s T_j = 25 °C$			1200	W
T <sub>stg</sub>	Storage temperature range	- 65 to + 150	°C		
Tj	Maximum operating junction temperature (1)			150	°C
dV/dt	Critical rate of rise of reverse voltage			10000	V/µs

<sup>1.</sup>  $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance

Symbol	Parameter Value					
D	Junction to ambient		SMA	120	°C/W	
□th(j-a)	R <sub>th(j-a)</sub> Junction to ambient	Lead length = 10 mm	DO-41	100	- C/VV	
В	Junction to lead		SMA	30	°C/W	
R <sub>th(j-l)</sub>	Junction to lead	Lead length = 10 mm	DO-41	45	C/VV	
R <sub>th(j-c)</sub>	Junction to case		STmite flat	20	°C/W	

Table 4. Static electrical characteristics

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
ı (1)	-\'/ I Reverse leakage current l	T <sub>j</sub> = 25 °C	V - V			50	μΑ
'R`		T <sub>j</sub> = 100 °C	$V_R = V_{RRM}$		1.5	5	mA
	V <sub>F</sub> <sup>(1)</sup> Forward voltage drop	T <sub>j</sub> = 25 °C				0.57	
		T <sub>j</sub> = 100 °C	I <sub>F</sub> = 1 A			0.56	
v (1)		T <sub>j</sub> = 125 °C			0.5	0.54	V
VF` ′		T <sub>j</sub> = 25 °C				0.75	V
		T <sub>j</sub> = 100 °C	I <sub>F</sub> = 2 A			0.68	
		T <sub>j</sub> = 125 °C			0.6	0.66	

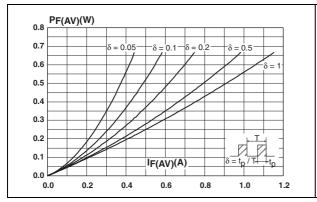
<sup>1.</sup> Pulse test:  $t_p = 380 \mu s$ ,  $\delta < 2\%$ 

To evaluate the conduction losses use the following equation: P = 0.44 x  $I_{F(AV)}$  + 0.12  $I_{F}^{2}_{(RMS)}$ 

$$P = 0.44 \times I_{F(AV)} + 0.12 I_{F^{2}(RMS)}$$

STPS1L60 Characteristics

Figure 1. Average forward power dissipation Figure 2. Average forward current versus ambient temperature ( $\delta$  = 0.5) (SMA)



1.0

1.0

R<sub>th(j-a)</sub> = R<sub>th(j-l)</sub>

0.8

0.6

0.4

0.2  $\delta = t_p/T - t_p$   $\delta = t_p/T - t_p$ Tamb(°C)

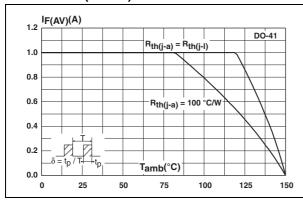
0.0

0.125

150

Figure 3. Average forward current versus ambient temperature ( $\delta$  = 0.5) (DO-41)

Figure 4. Average forward current versus ambient temperature ( $\delta$  = 0.5) (STmite flat)



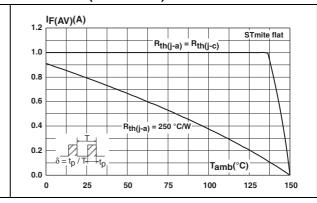
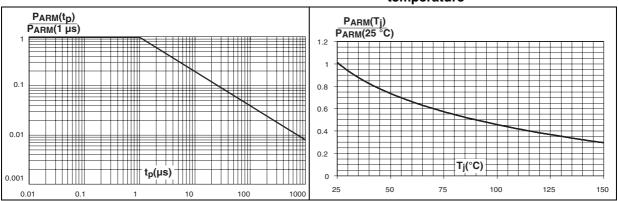


Figure 5. Normalized avalanche power derating versus pulse duration

Figure 6. Normalized avalanche power derating versus junction temperature



Characteristics STPS1L60

Figure 8.

Figure 7. Non repetitive surge peak forward current versus overload duration (maximum values) (SMA)

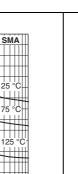
I<sub>M</sub>(A)

5

3

2

1.E-04



Non repetitive surge peak forward current versus overload duration (maximum values) (DO-41)

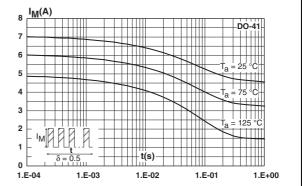
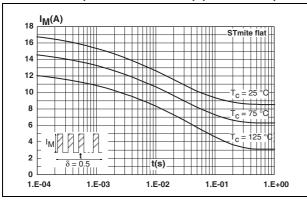


Figure 9. Non repetitive surge peak forward current versus overload duration (maximum values) (STmite flat)

Figure 10. Relative variation of thermal impedance junction to ambient versus pulse duration (SMA)



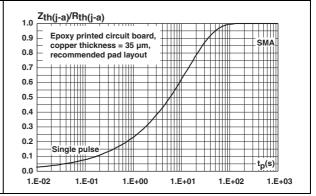
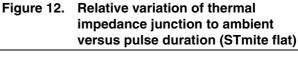
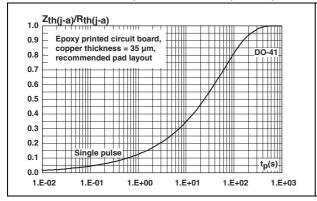
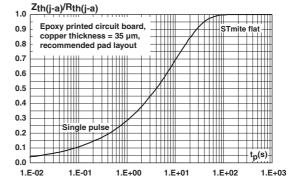


Figure 11. Relative variation of thermal impedance junction to ambient versus pulse duration (DO-41)







STPS1L60 Characteristics

Figure 13. Reverse leakage current versus reverse voltage applied (typical values)

Figure 14. Junction capacitance versus reverse voltage applied (typical values)

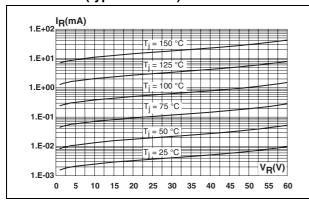
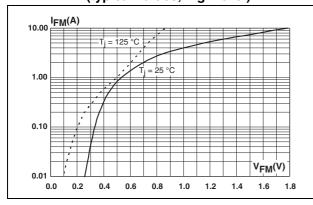
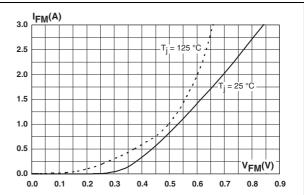


Figure 15. Forward voltage drop versus forward current (typical values, high level)

Figure 16. Forward voltage drop versus forward current (typical values, low level)

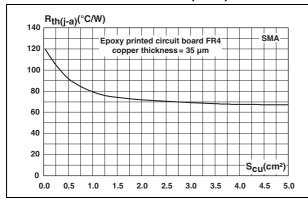




Characteristics STPS1L60

Figure 17. Thermal resistance junction to ambient versus copper surface under each lead (SMA)

Figure 18. Thermal resistance versus lead length (DO-41)



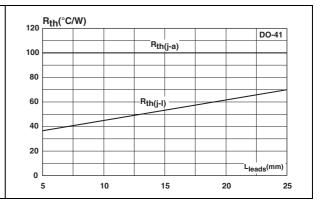
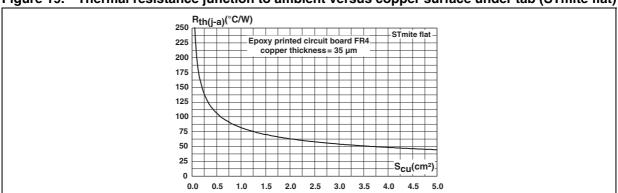


Figure 19. Thermal resistance junction to ambient versus copper surface under tab (STmite flat)



6/10 Doc ID 7504 Rev 8

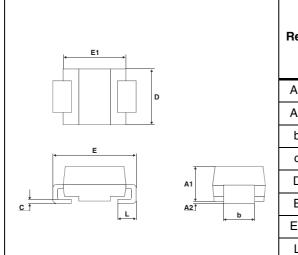
STPS1L60 Package information

# 2 Package information

- Epoxy meets UL94, V0
- Band indicates cathode

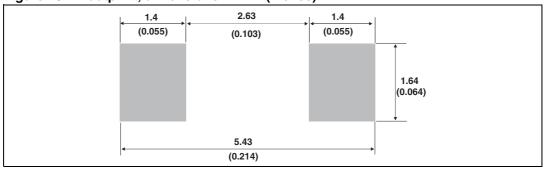
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Table 5. SMA dimensions



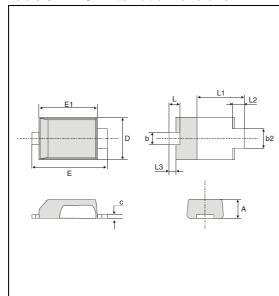
	Dimensions					
Ref.	Millim	neters	Inches			
	Min.	Max.	Min.	Max.		
A1	1.90	2.45	0.075	0.094		
A2	0.05	0.20	0.002	0.008		
b	1.25	1.65	0.049	0.065		
С	0.15	0.40	0.006	0.016		
D	2.25	2.90	0.089	0.114		
Е	4.80	5.35	0.189	0.211		
E1	3.95	4.60	0.156	0.181		
L	0.75	1.50	0.030	0.059		

Figure 20. Footprint, dimensions in mm (inches)



Package information STPS1L60

Table 6. STmite flat dimensions



	Dimensions					
Ref.	M	illimete	ers	Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	0.80	0.85	0.95	0.031	0.033	0.037
b	0.40	0.55	0.65	0.016	0.022	0.026
b2	0.70	0.85	1.00	0.027	0.033	0.039
С	0.10	0.15	0.25	0.004	0.006	0.009
D	1.75	1.90	2.05	0.069	0.075	0.081
Е	3.60	3.80	3.90	0.142	0.150	0.154
E1	2.80	2.95	3.10	0.110	0.116	0.122
L	0.50	0.55	0.80	0.020	0.022	0.031
L1	2.10	2.40	2.60	0.083	0.094	0.102
L2	0.45	0.60	0.75	0.018	0.024	0.030
L3	0.20	0.35	0.50	0.008	0.014	0.020

Figure 21. Footprint dimensions

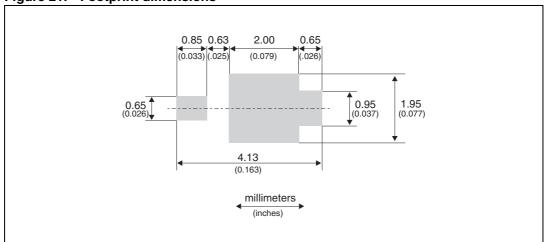
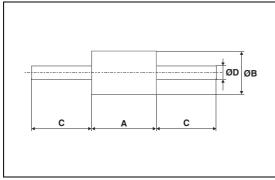


Table 7. DO-41 (plastic) dimensions



	Dimensions					
Ref.	Millimeters		Inc	hes		
	Min.	Max.	Min.	Max.		
Α	4.07	5.20	0.160	0.205		
В	2.04	2.71	0.080	0.107		
С	25.4		1			
D	0.71	0.86	0.028	0.034		

# 3 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS1L60A	GB6	SMA	0.068 g	5000	Tape and reel
STPS1L60	STPS1L60	DO-41	0.34 g	2000	Ammopack
STPS1L60RL	STPS1L60	DO-41	0.34 g	5000	Tape and reel
STPS1L60MF	F1L6	STmite flat	0.016 g	12000	Tape and reel

# 4 Revision history

Table 9. Document revision history

Date	Revision	Changes
Jul-2003	5A	Last update.
Aug-2004	6	SMA package dimensions update. Reference A1 max changed from 2.70 mm (0.106 inc.) to 2.03 mm (0.080 inc).
25-Jun-2009	7	Added package STmite flat. Updated ECOPACK statement.
30-Sep-2009	8	Updated table 7 ref. " C ".

#### Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2009 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

10/10 Doc ID 7504 Rev 8